Preferred Device

SWITCHMODESchottky Power Rectifier

Surface Mount Power Package

This series of Power Rectifiers employs the Schottky Barrier principle in a large metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use in low voltage, high frequency switching power supplies, free wheeling diodes, and polarity protection diodes.

Features

- · Guardring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Short Heat Sink Tab Manufactured Not Sheared!
- AEC-Q101 Qualified and PPAP Capable
- SBRB and SBRD8 Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free*

Mechanical Characteristics:

- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0
- Weight: 1.7 grams for D²PAK (approximately) 0.4 grams for DPAK (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL1 Requirements
- ESD Ratings:
 - ♦ Machine Model = C (> 400 V)
 - ♦ Human Body Model = 3B (> 8000 V)



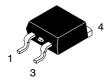
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 10 AMPERES, 45 VOLTS



MARKING DIAGRAM







A = Assembly Location Y = Year WW = Work Week MBRB1045 = Device Code

MBRB1045 = Device Code
G = Pb-Free Package
AKA = Diode Polarity

MARKING DIAGRAM





Y = Year

WW = Work Week

B1045 = Device Code

G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (Rated V _R) T _C = 135°C	I _{F(AV)}	10	Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _C = 135°C	I _{FRM}	20	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	150 (MBRB/SBRB) 70 (MBRD/SBRD)	А
Operating Junction and Storage Temperature Range (Note 1)	T _J , T _{stg}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, (MBRB1045G)			°C/W
Junction-to-Case (Note 2) Junction-to-Ambient (Note 2)	$R_{ hetaJC} \ R_{ hetaJA}$	1.0 50	
(MBRD1045G) Junction-to-Case (Note 2) Junction-to-Ambient (Note 2)	$R_{ hetaJC} \ R_{ hetaJA}$	2.43 68	

^{2.} When mounted using minimum recommended pad size on FR-4 board.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 3) ($I_F = 10 \text{ Amps}, T_J = 125^{\circ}\text{C}$) ($I_F = 20 \text{ Amps}, T_J = 125^{\circ}\text{C}$) ($I_F = 20 \text{ Amps}, T_J = 25^{\circ}\text{C}$)	V _F	0.57 0.72 0.84	V
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, T_J = 125°C) (Rated dc Voltage, T_J = 25°C)	I _R	15 0.1	mA

^{3.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

ORDERING INFORMATION

Device	Package	Shipping [†]	
MBRB1045G	D ² PAK (Pb-Free)	50 Units / Rail	
SBRB1045G	D ² PAK (Pb-Free)	50 Units / Rail	
MBRB1045T4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel	
SBRB1045T4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel	
MBRD1045G	DPAK (Pb-Free)	50 Units / Rail	
MBRD1045T4G	DPAK (Pb-Free)	2,500 Units / Tape & Reel	
SBRD81045T4G	DPAK (Pb-Free)	2,500 Units / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

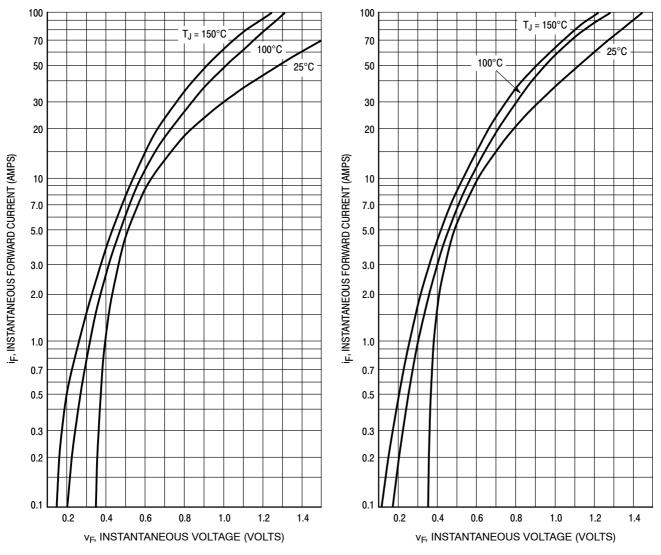


Figure 1. Maximum Forward Voltage

 $T_J = 150$ °C

125°C

100°C

25°C

20

100

10

1.0

0.1

0.01

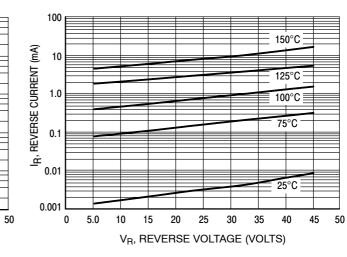
0.001

5.0

10

15

REVERSE CURRENT (mA)



V_R, REVERSE VOLTAGE (VOLTS)

25

30

40

45

Figure 3. Maximum Reverse Current Figure 4. Typical Reverse Current

Figure 2. Typical Forward Voltage

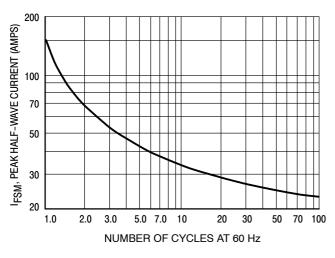


Figure 8. Maximum Surge Capability

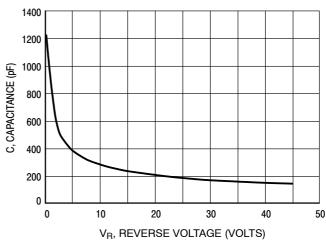


Figure 5. Typical Capacitance

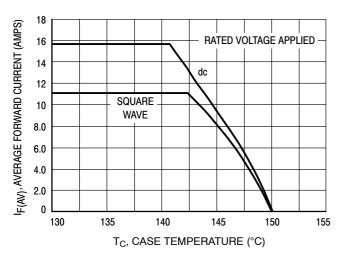


Figure 6. Current Derating, Case, $R_{\theta JC} = 1.0 \, ^{\circ}\text{C/W}$

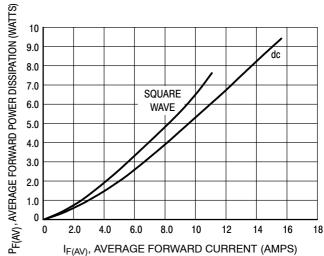
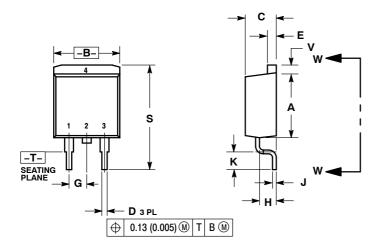


Figure 7. Forward Power Dissipation

PACKAGE DIMENSIONS

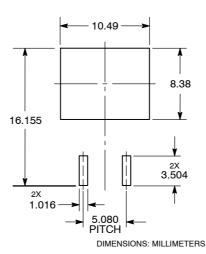
D²PAK 3 CASE 418B-04 ISSUE K



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
E	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
М	0.280	0.320	7.11	8.13
N	0.197	7 REF 5.00 REF		REF
P	0.079 REF		2.00 REF	
R	0.039 REF		0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40

SOLDERING FOOTPRINT*

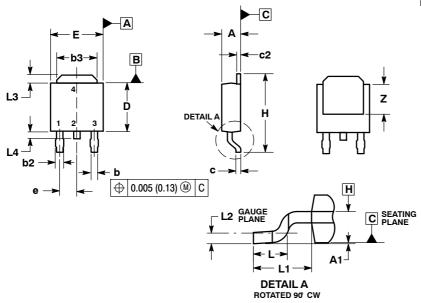


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C-01 ISSUE D

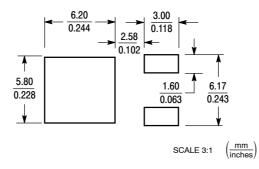


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M. 1994.
- 2. CONTROLLING DIMENSION: INCHES.
- THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020	0.020 BSC		BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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